

# **ISC Silicon NPN Power Transistor**

**BUY29** 

#### **DESCRIPTION**

- Collector-Emitter Breakdown Voltage-:V<sub>(BR)CEO</sub>= 200V(Min.)
- Excellent Safe Operating Area
- · High Speed Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## **APPLICATIONS**

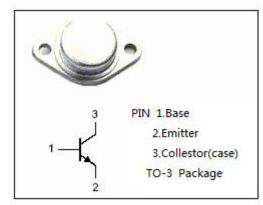
• Designed for use in switching-control amplifiers, power gates, switching regulators, converters, and inverter.

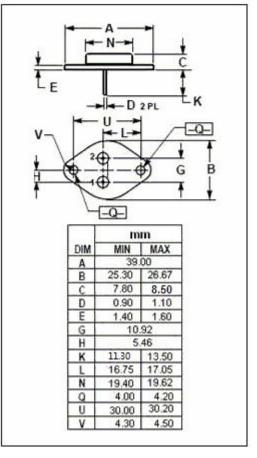
## ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25℃)

ABSOLUTE WITH MITHURS (1a 25 C)							
SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>CBO</sub>	Collector-Base Voltage	250	V				
V <sub>CEO</sub>	Collector-Emitter Voltage	200	V				
V <sub>EBO</sub>	Emitter-Base Voltage	7	V				
Ic	Collector Current-Continuous	8	Α				
Ісм	Collector Current-Peak	12	Α				
lΒ	Base Current-Continuous	2	Α				
P <sub>T</sub>	Total Power Dissipation @ T <sub>c</sub> ≤25 °C	125	W				
TJ	Junction Temperature	175	${\mathbb C}$				
T <sub>stg</sub>	Storage Temperature Range	-65~175	${\mathbb C}$				

# THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	1.17	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 50mA ;I <sub>B</sub> = 0	200			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 6A; I <sub>B</sub> = 1.2A			1.5	٧
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 6A; I <sub>B</sub> = 1.2A			2.0	٧
$V_{\text{BE(on)}}$	Base-Emitter Saturation Voltage	Ic= 6A; Vc== 3V			1.5	٧
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> =250V; I <sub>E</sub> =0			0.1	mA
I <sub>EBO</sub>	Emitter Cutoff current	V <sub>EB</sub> =6V; I <sub>C</sub> =0			0.1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V	60			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 3A ; V <sub>CE</sub> = 5V	15			
h <sub>FE-3</sub>	DC Current Gain	Ic= 8A ; V <sub>CE</sub> = 5V	10			

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